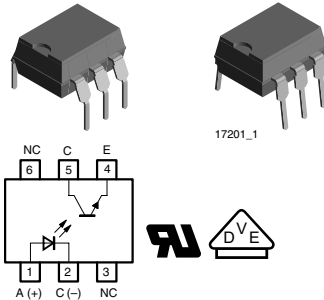


## Optocoupler, Phototransistor Output



### DESCRIPTION

The TCDT1110/TCDT1110G consists of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 6 pin plastic dual in line package. The elements provide a fixed distance between input and output for highest safety requirements.

### VDE STANDARDS

These couplers perform safety functions according to the following equipment standards:

- **DIN EN 60747-5-5**  
Optocoupler for electrical safety requirements
- **IEC 60950/EN 60950**  
Office machines (applied for reinforced isolation for mains voltage  $\leq 400 V_{RMS}$ )
- **VDE 0804**  
Telecommunication apparatus and data processing
- **IEC 60065**  
Safety for mains-operated electronic and related household apparatus

### FEATURES

- Extra low coupling capacity - typical 0.2 pF
- High Common Mode Rejection
- Low temperature coefficient of CTR
- Base not connected
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



### APPLICATIONS

- Switch-mode power supplies
- Line receiver
- Computer peripheral interface
- Microprocessor system interface
- Circuits for safe protective separation against electrical shock according to safety class II (reinforced isolation):
  - For appl. class I - IV at mains voltage  $\leq 300 V$
  - For appl. class I - III at mains voltage  $\leq 600 V$  according DIN EN 60747-5-5.

### AGENCY APPROVALS

- UL1577, File No. E76222 System Code A, Double Protection
- BSI IEC 60950; IEC 60065
- DIN EN 60747-5-5 pending
- FIMKO

### ORDER INFORMATION

PART	REMARKS
TCDT1110	CTR > 100 %, DIP-6
TCDT1110G	CTR > 100 %, DIP-6

#### Note

G = Leadform 10.16 mm; G is not marked on the body.

### ABSOLUTE MAXIMUM RATINGS (1)

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
<b>INPUT</b>				
Reverse voltage		$V_R$	6	V
Forward current		$I_F$	60	mA
Forward surge current	$t_p/T \leq 10 \mu s$	$I_{FSM}$	3	A
Power dissipation		$P_{diss}$	100	mW
Junction temperature		$T_j$	125	°C

ABSOLUTE MAXIMUM RATINGS (1)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
<b>OUTPUT</b>				
Collector emitter voltage		$V_{CEO}$	70	V
Emitter collector voltage		$V_{ECO}$	7	V
Collector current		$I_C$	50	mA
Collector peak current	$t_p/T = 0.5, t_p \leq 10 \text{ ms}$	$I_{CM}$	100	mA
Power dissipation		$P_{diss}$	150	mW
Junction temperature		$T_j$	125	°C
<b>COUPLER</b>				
Isolation test voltage (RMS)	$t = 1 \text{ min}$	$V_{ISO}$	5300	$V_{RMS}$
Total power dissipation		$P_{tot}$	250	mw
Ambient temperature range		$T_{amb}$	- 55 to + 100	°C
Storage temperature range		$T_{stg}$	- 55 to + 125	°C
Soldering temperature (2)	2 mm from case $t \leq 10 \text{ s}$	$T_{sld}$	260	°C

### Notes

(1)  $T_{amb} = 25 \text{ °C}$  unless otherwise specified. Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

(2) Refer to wave profile for soldering conditions for through hole devices.

ELECTRICAL CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
<b>INPUT</b>						
Forward voltage	$I_F = 50 \text{ mA}$	$V_F$		1.2	1.5	V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$	$C_j$		50		pF
<b>OUTPUT</b>						
Collector emitter voltage	$I_C = 1 \text{ mA}$	$V_{CEO}$	70			V
Emitter collector voltage	$I_E = 100 \text{ }\mu\text{A}$	$V_{ECO}$	7			V
Collector-emitter cut-off current	$V_{CE} = 30 \text{ V}, I_F = 0$	$I_{CEO}$			150	nA
<b>COUPLER</b>						
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 0.5 \text{ mA}$	$V_{CEsat}$			0.3	V
Cut-off frequency	$V_{CE} = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 1 \text{ }\Omega$	$f_c$		110		kHz
Coupling capacitance	$f = 1 \text{ MHz}$	$C_k$		0.3		pF

### Note

$T_{amb} = 25 \text{ °C}$  unless otherwise specified.

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
$I_C/I_F$	$V_{CE} = 20 \text{ V}, I_F = 10 \text{ mA}$	CTR	100			%

MAXIMUM SAFETY RATINGS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
<b>INPUT</b>						
Forward current		$I_F$			130	mA
<b>OUTPUT</b>						
Power dissipation		$P_{diss}$			265	mW
<b>COUPLER</b>						
Rated impulse voltage		$V_{IOTM}$			6	kV
Safety temperature		$T_{si}$			150	°C

### Note

According to DIN EN 60747-5-5 see figure 1. This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

INSULATION RATED PARAMETERS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Partial discharge test voltage - routine test	100 %, $t_{test} = 1$ s	$V_{pd}$	1.6			kV
Partial discharge test voltage - lot test (sample test)	$t_{Tr} = 60$ s, $t_{test} = 10$ s, (see figure 2)	$V_{IOTM}$	6			kV
		$V_{pd}$	1.3			kV
Insulation resistance	$V_{IO} = 500$ V	$R_{IO}$	$10^{12}$			$\Omega$
	$V_{IO} = 500$ V, $T_{amb} = 100$ °C	$R_{IO}$	$10^{11}$			$\Omega$
	$V_{IO} = 500$ V, $T_{amb} = 200$ °C (construction test only)	$R_{IO}$	$10^9$			$\Omega$

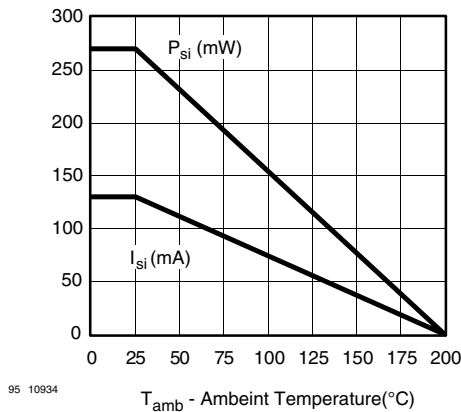


Fig. 3 - Derating diagram

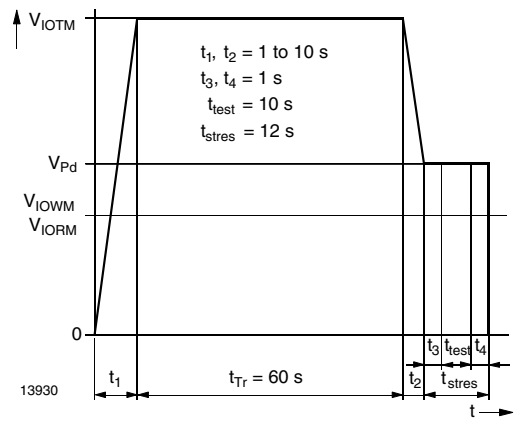


Fig. 4 - Test Pulse Diagram for Sample Test According to DIN EN 60747-5-5/DIN EN 60747-; IEC 60747

SWITCHING CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Turn-off time	$V_S = 10$ V, $I_C = 2$ mA, $R_L = 100$ $\Omega$ (see figure 3)	$t_{off}$		15.0		$\mu$ s
Turn-on time	$V_S = 10$ V, $I_C = 2$ mA, $R_L = 100$ $\Omega$ (see figure 3)	$t_{on}$		15.0		$\mu$ s
Turn-off time	$V_S = 10$ V, $I_F = 10$ mA, $R_L = 1$ k $\Omega$ (see figure 4)	$t_{off}$		18.0		$\mu$ s
Turn-on time	$V_S = 10$ V, $I_F = 10$ mA, $R_L = 1$ k $\Omega$ (see figure 4)	$t_{on}$		9.0		$\mu$ s

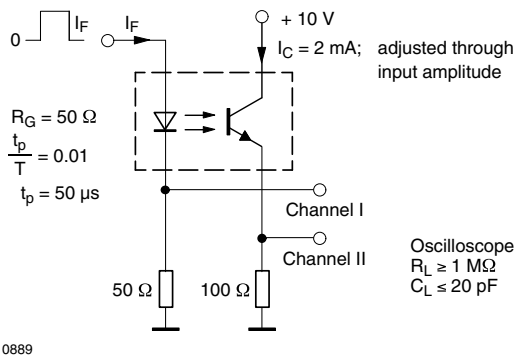


Fig. 5 - Test Circuit, Non-Saturated Operation

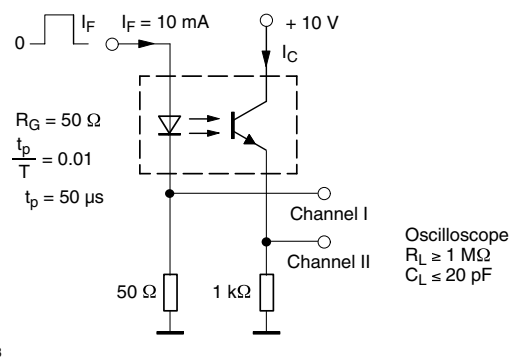


Fig. 6 - Test Circuit, Saturated Operation

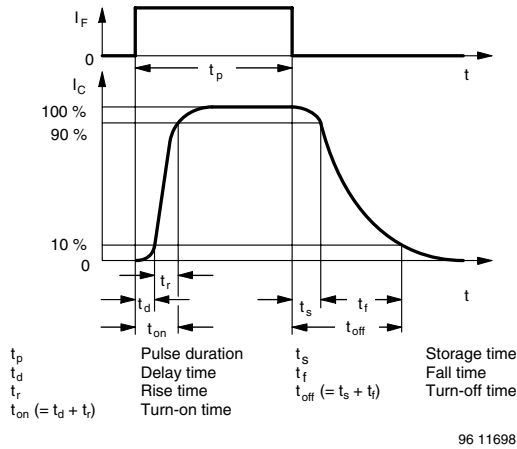


Fig. 7 - Switching Times

## TYPICAL CHARACTERISTICS

$T_{amb} = 25\text{ }^\circ\text{C}$ , unless otherwise specified

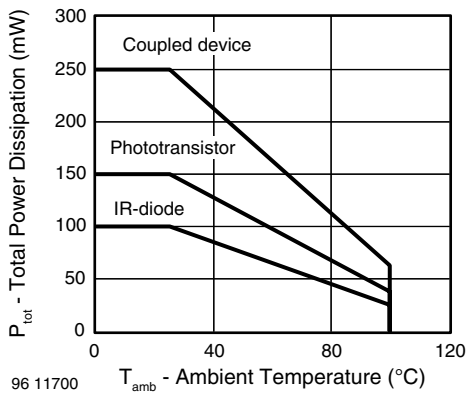


Fig. 8 - Total Power Dissipation vs. Ambient Temperature

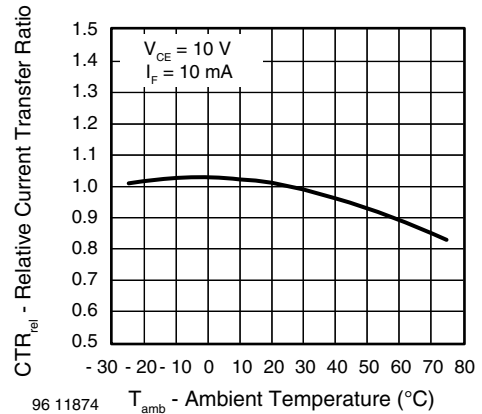


Fig. 10 - Relative Current Transfer Ratio vs. Ambient Temperature

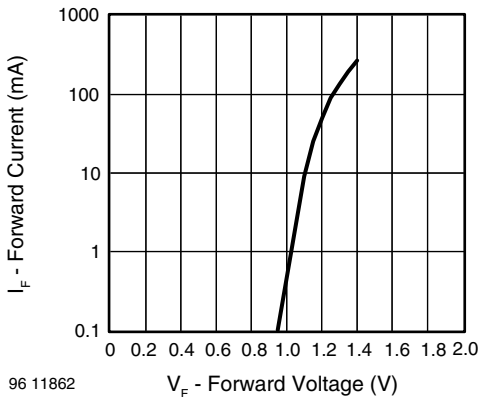


Fig. 9 - Forward Current vs. Forward Voltage

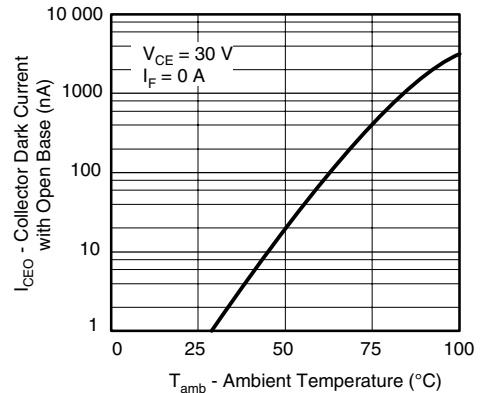


Fig. 11 - Collector Dark Current vs. Ambient Temperature

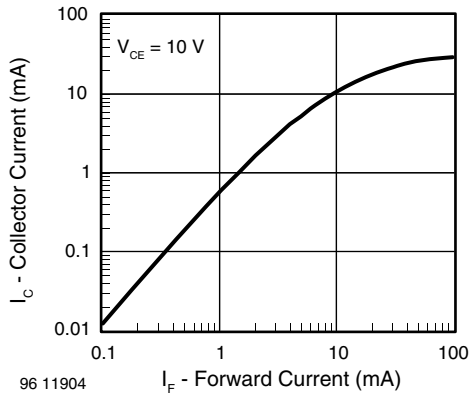


Fig. 12 - Collector Current vs. Forward Current

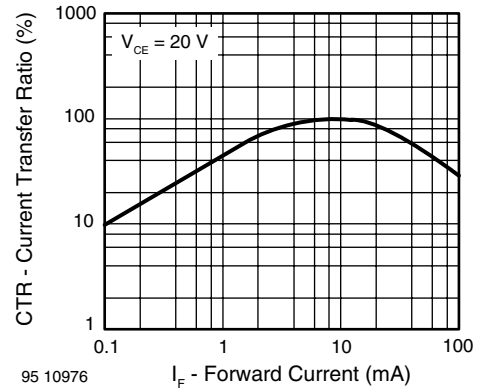


Fig. 15 - Current Transfer Ratio vs. Forward Current

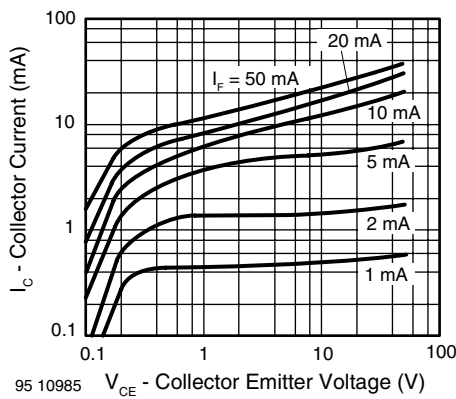


Fig. 13 - Collector Current vs. Collector Emitter Voltage

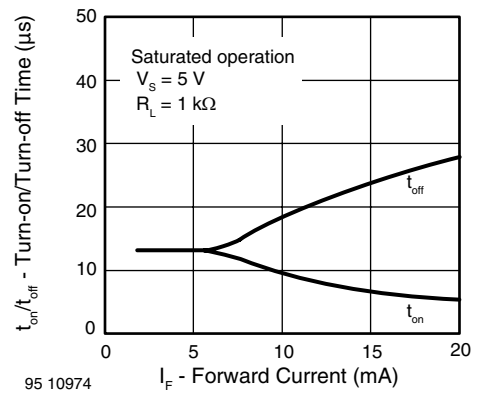


Fig. 16 - Turn-on/Turn-off Time vs. Forward Current

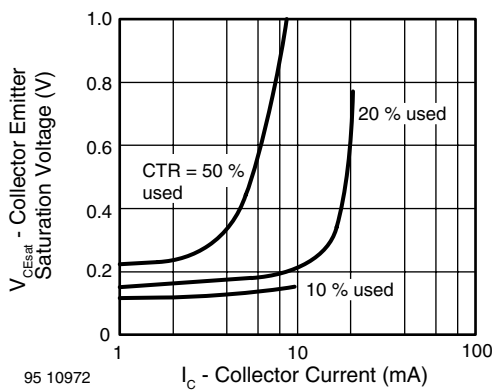


Fig. 14 - Collector Emitter Saturation Voltage vs. Collector Current

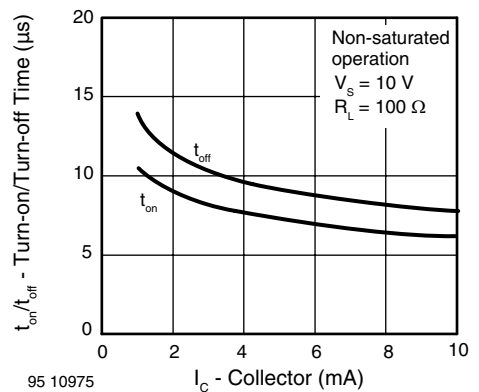


Fig. 17 - Turn-on/Turn-off Time vs. Collector Current

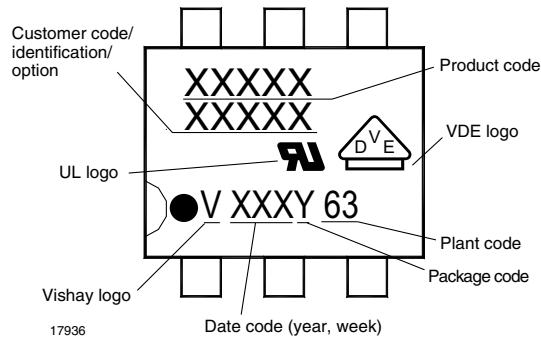
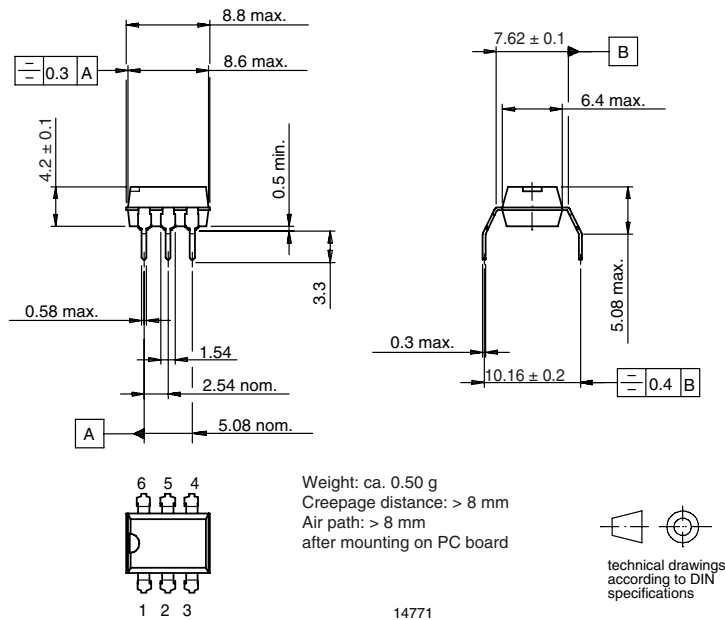
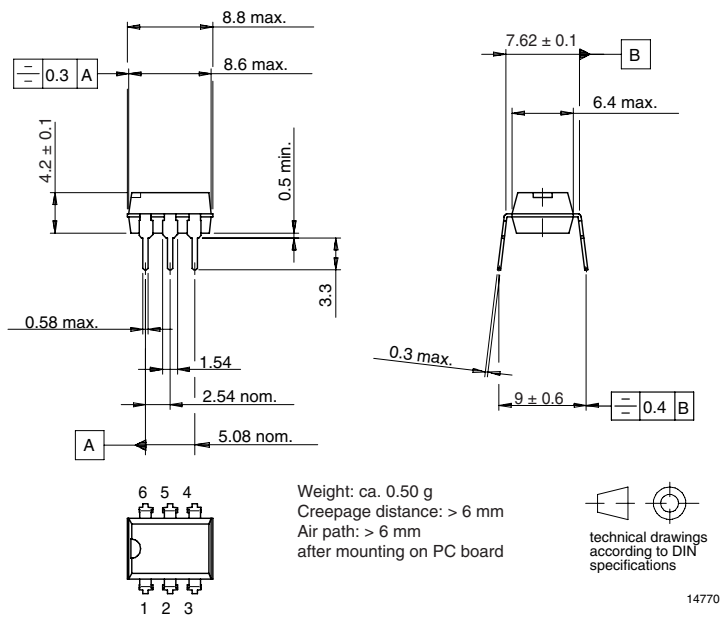


Fig. 18 - Marking example

## PACKAGE DIMENSIONS in millimeters



**OZONE DEPLETING SUBSTANCES POLICY STATEMENT**

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design  
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.



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- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
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- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

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- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

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